

#### **Product Summary**

BV <sub>DSS</sub>	Rds(on) Max	I <sub>D Max</sub> T <sub>A</sub> = +25°С
60V	0.08Ω @ V <sub>GS</sub> = 10V	5.3A
	0.15Ω @ V <sub>GS</sub> = 4.5V	2.8A

This MOSFET is designed to meet the stringent requirements of

automotive applications. It is qualified to AEC-Q101, supported by a

#### **Features and Benefits**

- Low On-Resistance
- Fast Switching Speed
- Low Threshold
- Low Gate Drive
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The ZXMN6A08GQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

# Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Solderable per MIL-STD-202, Method 208(e3)
- Weight: 0.112 grams (Approximate)



SOT223 (Type ZN)

**Description and Applications** 

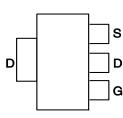
PPAP and is ideal for use in:

**DC-DC Converters** 

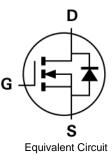
**BLDC Motors** 

Load Switch

Top View



Pin Out - Top View



# Ordering Information (Note 4)

Part Number	Case	Packaging
ZXMN6A08GQTA	SOT223 (Type ZN)	1000/Tape & Reel
ZXMN6A08GQTC	SOT223 (Type ZN)	4000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

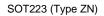
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

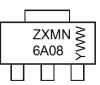
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**

Notes:





ZXMN6A08 = Product Type Marking Code YWW = Date Code Marking Y = Last Digit of Year (ex: 0 = 2020) WW = Week Code (01 to 53)



### **Maximum Ratings**

Characteristic Drain-Source Voltage		Symbol	Value	Unit V
		Vdss	60	
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
	T <sub>A</sub> = +25°C (Note 6)		5.3	А
Continuous Drain Current @ V <sub>GS</sub> = 10V	$T_A = +70^{\circ}C$ (Note 6)	ID	4.2	А
	$T_A = +25^{\circ}C$ (Note 5)		3.8	А
Pulsed Drain Current (Note 7)		I <sub>DM</sub>	20	А
Continuous Source Current (Body Diode) (Note 6)		ls	2.1	А
Pulsed Source Current (Body Diode) (Note 7)		Ism	20	А
Power Dissipation at T <sub>A</sub> = +25°C (Note 5) Linear Derating Factor		PD	2 16	W mW/°C
Power Dissipation at $T_A = +25^{\circ}C$ (Note 6) Linear Derating Factor		PD	3.9 31	W mW/°C
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Junction to Ambient (Note 5)	R <sub>0JA</sub>	62.5	°C/W
Junction to Ambient (Note 6)	Reja	32	°C/W

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

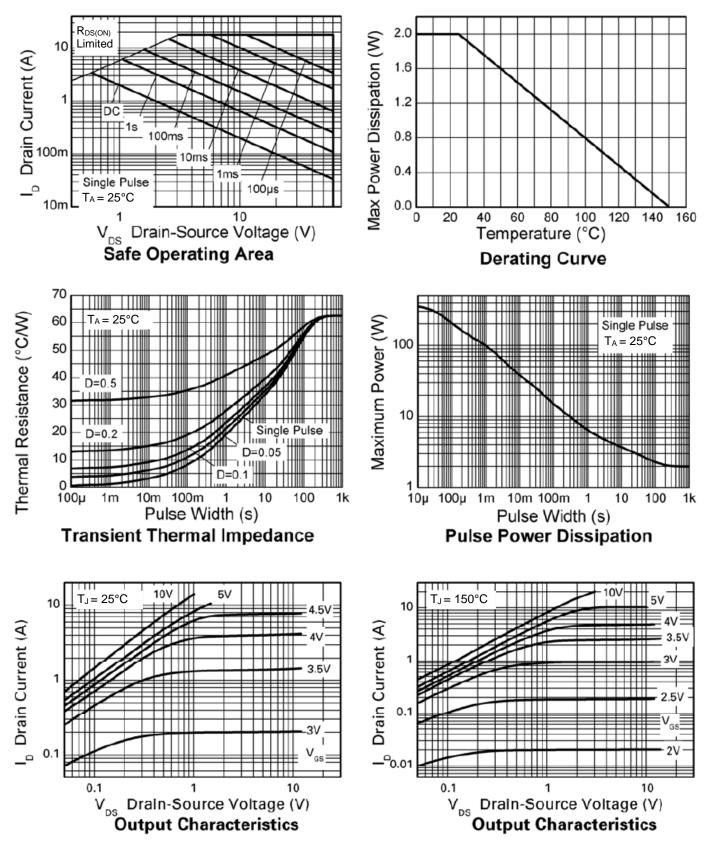
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BVDSS	60	—	—	V	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250µA	
Zero Gate Voltage Drain Current	IDSS		_	0.5	μA	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS		—	100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS	· · · · · ·					-	
Gate Threshold Voltage	VGS(TH)	1	_	_	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
		_	0.06	0.08	Ω	VGS = 10V, ID = 4.8A	
Static Drain-Source On-State Resistance	Rds(on)	_	0.08	0.15	Ω	Vgs = 4.5V, ID = 4.2A	
Forward Transconductance (Note 9)		_	6.6	_	S	V <sub>DS</sub> = 15V, I <sub>D</sub> = 4.8A	
Diode Forward Voltage	Vsd	_	0.88	1.2	V	$T_J = +25^{\circ}C$ , $I_S = 4A$ , $V_{GS} = 0V$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	_	459	_	pF		
Output Capacitance	Coss	_	44.2	_	pF	VDS = 40V, VGS = 0V, f = 1MHz	
Reverse Transfer Capacitance	Crss		24.1	_	pF		
Turn-On Delay Time (Note 8)	td(on)		2.6	_	ns		
Turn-On Rise Time (Note 8)	tR		2.1	_	ns	V <sub>DD</sub> = 30V, I <sub>D</sub> =1.5A	
Turn-Off Delay Time (Note 8)	t <sub>D(OFF)</sub>	_	12.3	_	ns	$R_G \cong 6.0\Omega, V_{GS} = 10V$	
Turn-Off Fall Time (Note 8)	tF		4.6	_	ns		
Gate Charge (Note 8)	QG	_	4.0	-	nC	$V_{DS} = 30V, V_{GS} = 5V$ $I_D = 1.4A$	
Total Gate Charge (Note 8)	QG	_	5.8	_	nC		
Gate-Source Charge (Note 8)	QGS	_	1.4	—	nC	$V_{DS} = 30V, V_{GS} = 10V$	
Gate Drain Charge (Note 8)	Q <sub>GD</sub>	_	1.9	—	nC	$I_{\rm D} = 1.4 {\rm A}$	
SOURCE-DRAIN DIODE							
Reverse Recovery Time (Note 9)	t <sub>RR</sub>	_	19.2	—	ns	T <sub>J</sub> = +25°C, I <sub>S</sub> = 1.4A,	
Reverse Recovery Charge (Note 9)	Qrr	_	30.3	_	nC	di/dt = 100A/µs	

6. For a device surface mounted on FR-4 PCB measured at  $t \le 10$ s.

7. Repetitive rating - 25mm × 25mm FR-4 PCB, D = 0.02, pulse width 300µs - pulse width limited by maximum junction temperature.

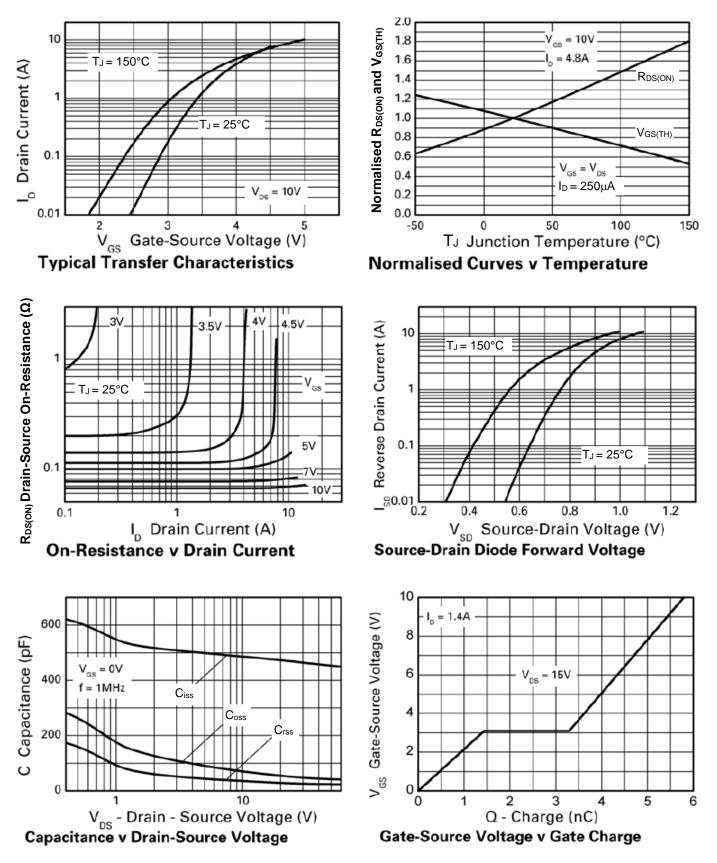
Switching characteristics are independent of operating junction temperature.
 For design aid only, not subject to production testing.





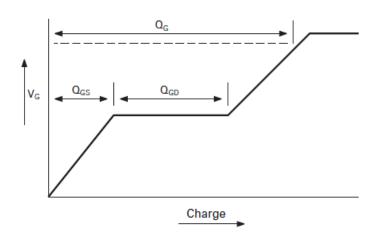


# ZXMN6A08GQ

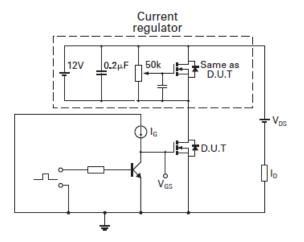




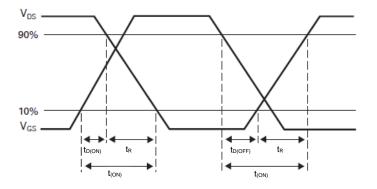
# **Test Circuits**



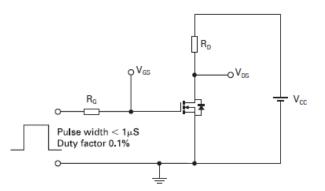




Gate charge test circuit



Switching time waveforms

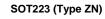


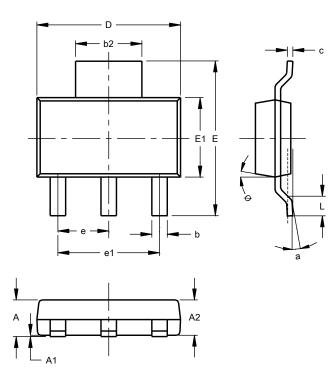
Switching time test circuit



### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

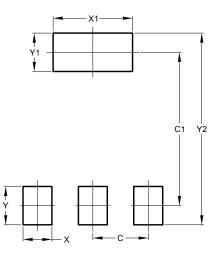




SOT223 (Type ZN)					
Dim	Min	Max	Тур		
Α		1.70			
A1	0.02	0.10			
A2	1.50	1.68	1.60		
b	0.60	0.80			
b2	2.90	3.10			
С	0.24	0.32			
D	6.30	6.70			
Е	6.70	7.30			
E1	3.30	3.70			
e	2.30 NOM				
e1	4.60 NOM				
L	0.90				
а			10°		
θ		15°			
All Dimensions in mm					

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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